# GaAs INTEGRATED CIRCUIT $\mu PG110P$

# 2 to 8 GHz WIDE BAND AMPLIFIER CHIP

## DESCRIPTION

NEC

The  $\mu$ PG110P is a GaAs monolithic integrated circuit designed as a wide band amplifier from 2 to 8 GHz. And the device is available in chip form. The  $\mu$ PG110P is suitable for the gain stage required high gain characteristic of the microwave communication system and the measurement equipment.

## FEATURES

- Ultra wide band : 2 to 8 GHz
- High Power Gain :  $G_P = 15 \text{ dB TYP}$ . @f = 2 to 8 GHz
- Medium Power :  $P_{O(1 dB)} = +14 dBm TYP$ . @f = 2 to 8 GHz

#### ORDERING INFORMATION

PART NUMBER	FORM			
μPG110P	Chip			

#### ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25 $^{\circ}$ C)

Supply Voltage	Vdd	+10	V
Input Voltage	Vin	-5 to +0.6	V
Input Power	Pin	+10	dBm
Total Power Dissipation	Ptot*1	1.5	W
Operating Temperature	Topr* <sup>2</sup>	-65 to +125	°C
Storage Temperature	Tstg	-65 to +125	°C

\*1 Mounted with AuSn hard solder

\*2 The temperature of base material beside the chip

# RECOMMENDED OPERATING CONDITIONS (TA = 25 °C)

Supply Voltage	Vdd	+8 ± 0.2	V
Input Power	Pin	-5	dBm

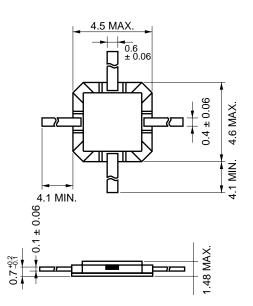
# ELECTRICAL CHARACTERISTICS (TA = 25 $^\circ\text{C})^{*3}$

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Supply Current	lod	65	135	180	mA	VDD = +8 V
Power Gain	G₽	12	15		dB	f = 2 to 8 GHz
Gain Flatness	⊿Gp			±1.5	dB	
Input Return Loss	RLin	6	10		dB	
Output Return Loss	RLout	7	10		dB	
Isolation	ISL	30	40		dB	
Output Power at 1 dB Gain Compression Point	Po(1 dB)	10	14		dBm	

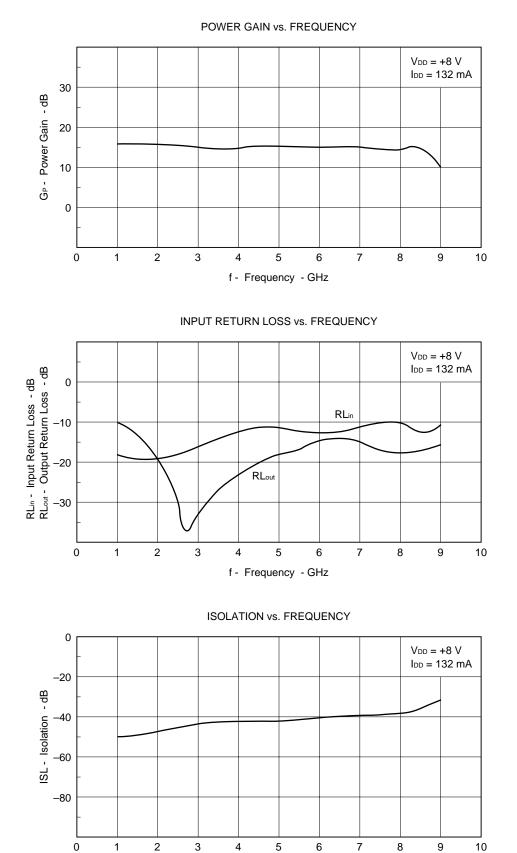
\*3 These characteristics are based on performance of devices mounted in the standard package shown in Fig. 1.

# Fig. 1 4 pin Ceramic Package

Top View

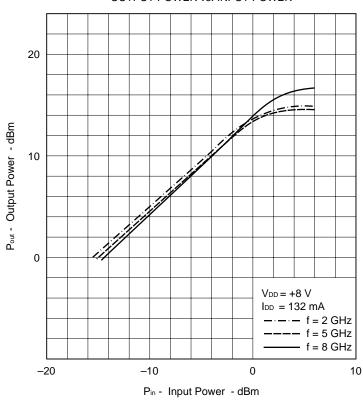


TYPICAL CHARACTERISTICS (TA = 25  $^\circ\text{C})^{*4}$ 



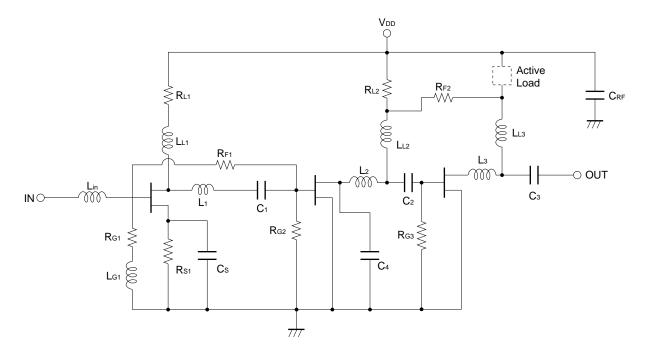
f - Frequency - GHz

3



#### \*4 These characteristics are measured for device mounted in the standard package shown in Fig. 1.





## **RECOMMENDED CHIP ASSEMBLY CONDITIONS**

#### **Die Attachment**

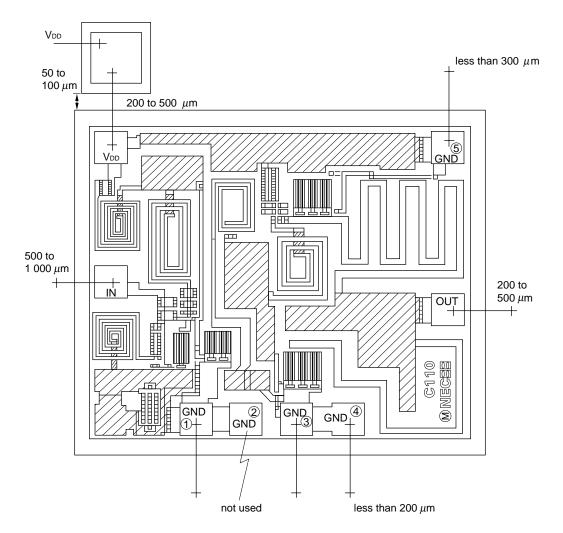
Atmosphere : N<sub>2</sub> gas Temperature : 320 ± 5 °C AuSn Preform : 0.5 × 0.5 × 0.05<sup>t</sup> (mm), 1 pce. \* The hard solder such as AuSi or AuGe which has higher melting point than AuSn should not be used. Base Material : CuW, Cu, KV \* Other material should not be used.

Epoxy Die Attach is not recommended.

#### Bonding

Machine	:	ТСВ
		* USB is not recommended
Wire	:	30 $\mu$ m diameter Au wire
Temperature	:	$260\pm5~^\circ\text{C}$
Strength	:	$31 \pm 3$ g
Atmosphere	:	N <sub>2</sub> gas

#### **Chip Bonding Diagram**



#### **Recommended Wire Length**

- 1. 500 to 1 000  $\mu$ m for Input (the longer the wire, the better the VSWR)
- 2. 200 to 500  $\mu m$  for Output (the shorter the wire, the better the VSWR)
- 3. It should be bonded via a chip capacitor for V\_DD. Wire length is 200 to 500  $\mu \rm m$
- 4. There are five GND pads but GND pad <2> is not used. Wire length is 200  $\mu$ m for <1>, <3> and <4>. Less than 300  $\mu$ m for <5>.

Chip Size:  $1.1 \times 1.3 \text{ mm}$ t = 140  $\mu$ m Pad Size :  $100 \times 100 \mu$ m

#### QUALITY ASSURANCE (Refer to GET-30116)

#### 1. 100 % Tests

- 1-1 100 % DC Probe
- 1-2 Visual Inspection MIL-STD-883 Method 2010 Condition B

#### 2. Tests on Sampling Basis

2-1 Bond Pull Tests (In case of recommended chip handling)

MIL-STD-883 Method 2011

5 samples/wafer and 20 points tested

Accept 0/Reject 1

2-2 Tests in Standard Package
Test the electrical characteristics of chips assembled into the standard package used for μPG110B
5 samples/wafer tested
DC and RF measurement Accept 1/Reject 2

#### 3. Warrantee

NEC has a responsibility of quality assurance for the products within 180 days after delivered to customers where these are handled properly and stored in a desiccater with the flow of dry  $N_2$  gas.

#### 4. Caution

- 4-1 Take great care to prevent static electricity.
- 4-2 Be sure that Die Attach is performed in  $N_{\rm 2}$  atmosphere.

# Caution

The Great Care must be taken in dealing with the devices in this guide. The reason is that the material of the devices is GaAs (Galium Arsenide), which is designated as harmful substance according to the law concerned. Keep the law concerned and so on, especially in case of removal.

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- Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
- Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
- Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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Anti-radioactive design is not implemented in this product.